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ANALOG DEVICES

CMOS 8- and 16-Channel Analog Multiplexers AD7506/AD7507

FEATURES R_{ON}: 300Ω Power Dissipation: 1.5mW TTL/DTL/CMOS Direct Interface Break-Before-Make Switching Standard 28-Pin DIPs and 28-Terminal Surface Mount Packages

The AD7506 is a monolithic CMOS 16-channel analog multiplexer packaged in a 28-pin DIP or a 28-terminal surface mount package. It switches a common output to one of 16 inputs, depending on

the state of four address lines and an "enable." The AD7507 is

identical to the AD7506 except it has two outputs switched to

two of 16 inputs depending on three binary address states and

Derates above + 50°C by 10mW/°C

 $\begin{array}{c} \mbox{Commercial (KN Versions)} \dots \dots \dots \dots 0 \mbox{ to } +70^\circ C \\ \mbox{Industrial (KQ Versions)} \dots \dots \dots -25^\circ C \mbox{ to } +85^\circ C \\ \mbox{Extended (TQ, TE Versions)} \dots \dots \dots -55^\circ C \mbox{ to } +125^\circ C \\ \mbox{Storage Temperature} \dots \dots \dots \dots -65^\circ C \mbox{ to } +150^\circ C \\ \mbox{Lead Temperature (Soldering, 10sec)} \dots \dots \dots +300^\circ C \\ \end{array}$

GENERAL DESCRIPTION

ABSOLUTE MAXIMUM RATINGS* $(T_A = +25^{\circ}C \text{ unless otherwise noted})$ $V_{DD} - GND \dots \dots \dots \dots \dots \dots$

Switch Current (I_S, Surge One Channel)

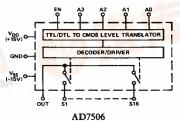
Power Dissipation (Any Package)

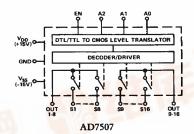
Operating Temperature

V Between Any Switch Terminals (see Note 1)

FUNCTIONAL DIAGRAMS

加急出货





ORDERING GUIDE

Model ¹	Temperature Range	Package Option ²	
AD7506KN	0°C to +70°C	N-28	
AD7506KQ	-25°C to +85°C	Q-28	
AD7506TQ	-55°C to +125°C	Q-28	
AD7506TE	-55°C to +125°C	E-28A	
AD7507KN	0°C to +70°C	N-28	
AD7507KQ	-25°C to +85°C	Q-28	
AD7507TQ	-55°C to +125°C	Q-28	
AD7507TE	-55°C to +125°C	E-28A	

CAUTION:

an "enable."

¹Do not apply voltage higher than V_{DD} and V_{SS} to any other terminal, especially when $V_{SS} = V_{DD} = 0V$ all other pins should be at 0V.

²The digital control inputs are diode protected; however, permanent damage may occur on unconnected units under high energy electrostatic fields. Keep unused units in conductive foam at all times.

*Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one Absolute Maximum Rating may be applied at any one time.



NOTES

+17V

· · · · 25V

. . 1000mW

¹To order MIL-STD-883, Class B, processed parts, add/883B to part number. See Analog Devices Military Products Databook (1990) for military data sheet.

 2 N = Plastic DIP; Q = Cerdip; E = Leadless Ceramic Chip Carrier (LCCC). For outline information see Package Information section.

AD7506/AD7507 — SPECIFICATIONS ($v_{00} = +15V$, $v_{ss} = -15V$ unless otherwise neted.)

Parameter	Version ¹	Switch Condition	@ +25°C	Over Specified Temperature Range	Test Conditions
ANALOG SWITCH				5500	$X = 10X + 0 \pm 10X$ $I = 1 = A$
R _{ON}	K T	ON ON	300Ω typ, 450Ω max 400Ω max	550Ω max 500Ω max	$V_{s} = -10V \text{ to } +10V, I_{s} = 1\text{mA}$
R _{ON} vs. V _S R _{ON} vs. Temperature AR _{ON} Between Switches R _{ON} vs. Temperature Between Switche	All All All s All	ON ON ON ON	15% typ 0.5%/°C typ 4% typ 0.05%/°C typ		$V_S = 0V, I_S = 1mA$
I _s (OFF)	K T	OFF OFF	0.05nA typ, 5nA max 0.05nA typ, 1nA max	50nA max 50nA max	$V_s = -10V$, $V_{OUT} = +10V$ and
I _{OUT} (OFF) AD7506	K T	OFF OFF	0.3nA typ, 20nA max 0.3nA typ, 10nA max	500nA max 500nA max	$V_s = +10V, V_{OUT} = -10V$ "Enable" Low
AD7507	K T	OFF OFF	0.3nA typ, 10nA max 0.3nA typ, 5nA max	250nA max 250nA max	
I _{OUT} -I _S AD7506 (Any Switch ON)	K T	ON ON	0.3nA typ, 20nA max 0.3nA typ, 10nA max	500nA max 500nA max	V _s =0V
AD7507	K T	ON ON	0.3nA typ, 10nA max 0.3nA typ, 5nA max	250nA max 250nA max	
DIGITAL CONTROL V _{INL} V _{INH}	All All			0.8V max 2.4V min	
I _{INL} or I _{INH}	All		10µA max	30µA max	
	All		3pF typ		
DYNAMIC CHARACTERISTICS ²	All		700ns typ, 1000ns max		V _{IN} : 0 to 3.0V
t _{OPEN}	All		100ns typ		
t _{on} (En)	All		1.5µs max		V _{EN} : 0 to 3.0V
t _{OFF} (En)	All		lµs max		
"OFF" Isolation	All		70dB typ		$V_{EN} = 0, R_L = 200\Omega, C_L = 3.0 pF$ $V_S = 3.0V rms, f = 50 kHz$
Cs	All	OFF	5pF typ		
C _{OUT} AD7506 AD7507	All All	OFF OFF	40pF typ 20pF typ		
C _{S-OUT}	All	OFF	0.5pF typ		
C _{SS} Between Any Two Switches	All	OFF	0.5pF typ		
POWER SUPPLY I _{DD}	K T	OFF OFF	0.05mA typ, 1mA max 0.05mA typ, 1mA max		All Digital Inputs Low
I _{SS}	K T	OFF OFF	0.05mA typ, 1mA mat 0.05mA typ, 1mA mat	K	
I _{DD}	K T	ON ON	0.3mA typ, 1mA max 0.3mA typ, 1mA max		All Digital Inputs High
I _{SS}	K T	ON ON	0.05mA typ, 1mA ma 0.05mA typ, 1mA ma	1	

NOTES

¹KN Version specified for 0 to +70°C; KQ Version for -25°C to +85°C; and TQ, TE Versions for -55°C to +125°C.

²Sample tested to ensure compliance.

Specifications subject to change without notice.

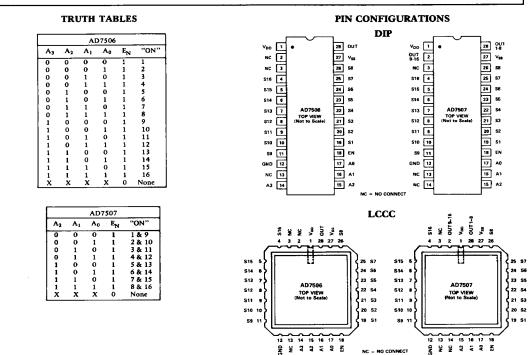
CAUTION .

ESD (electrostatic discharge) sensitive device. The digital control inputs are diode protected; however, permanent damage may occur on unconnected devices subject to high energy electrostatic fields. Unused devices must be stored in conductive foam or shunts. The protective foam should be discharged to the destination socket before devices are removed.



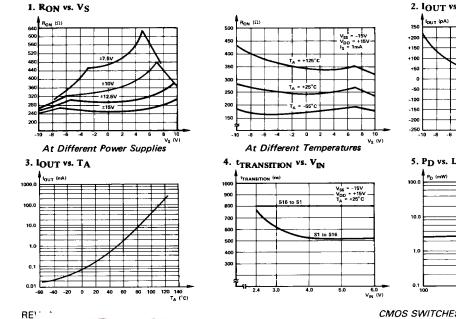
TIPLEXERS

AD7506/AD7507



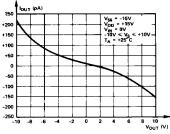
Typical Performance Characteristics

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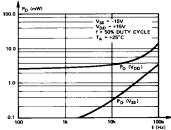


2. IOUT vs. VOUT

NC = NO CONNECT



5. PD vs. Logic Frequency

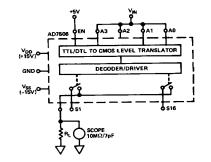


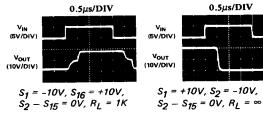
CMOS SWITCHES & MULTIPLEXERS 5-15

AD7506/AD7507

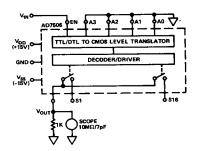
TYPICAL SWITCHING CHARACTERISTICS

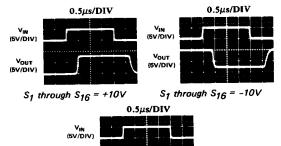
TEST CIRCUIT 1

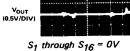




TEST CIRCUIT 2







TIPLEXERS